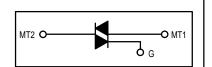
Advance Information **TRIACS** Silicon Bidirectional Thyristors

Designed for high performance full–wave ac control applications where high noise immunity and commutating di/dt are required.

- Blocking Voltage to 800 Volts
- On–State Current Rating of 12 Amperes RMS at 70°C
- Uniform Gate Trigger currents in Three Modes
- High Immunity to dv/dt 250 V/μs minimum at 125°C
- High Commutating di/dt 6.5 A/ms minimum at 125°C
- Industry Standard TO-220 AB Package
- High Surge Current Capability 120 Amperes



MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Parameter		Symbol		Value		Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ ($T_J = -40$ to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)	MAC12D MAC12M MAC12N	VDRI	Л	400 600 800)	Volts
On–State RMS Current (Full Cycle Sine Wave, 60 Hz, T _C = 70°C)		IT(RM	S)	12		A
Peak Non–repetitive Surge Current (One Full Cycle, 60 Hz, T _J = 125°C)		ITSM		100		A
Circuit Fusing Consideration (t = 8.3 ms)		l ² t		41		A ² sec
Peak Gate Power (Pulse Width \leq 1.0 µs, T _C = 80°C)		PGM		16		Watts
Average Gate Power (t = 8.3 ms, $T_C = 80^{\circ}C$)		P _{G(A}	/)	0.35		Watts
Operating Junction Temperature Range		ТJ		-40 to +125		°C
Storage Temperature Range		T _{stg}		-40 to +150		°C
HERMAL CHARACTERISTICS						
nal Resistance — Junction to Case — Junction to Ambient		R _{θJC} R _{θJA}		2.2 62.5		°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case	" from Case for 10 Seconds			260		°C
ELECTRICAL CHARACTERISTICS (T _J = 25° C unless otherwise	noted)					
Characteristic	Syn	nbol	Min	Тур	Max	Unit

OFF CHARACTERISTICS						
Peak Repetitive Blocking Current $(V_D = Rated V_{DRM}, Gate Open)$	TJ = 25°C TJ = 125°C	IDRM	—	—	0.01 2.0	mA

(1) V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

This document contains information on a new product. Specifications and information herein are subject to change without notice.

Preferred devices are Motorola recommended choices for future use and best overall value.

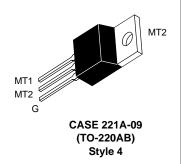
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*Motorola preferred devices

TRIACS 12 AMPERES RMS 400 thru 800 VOLTS



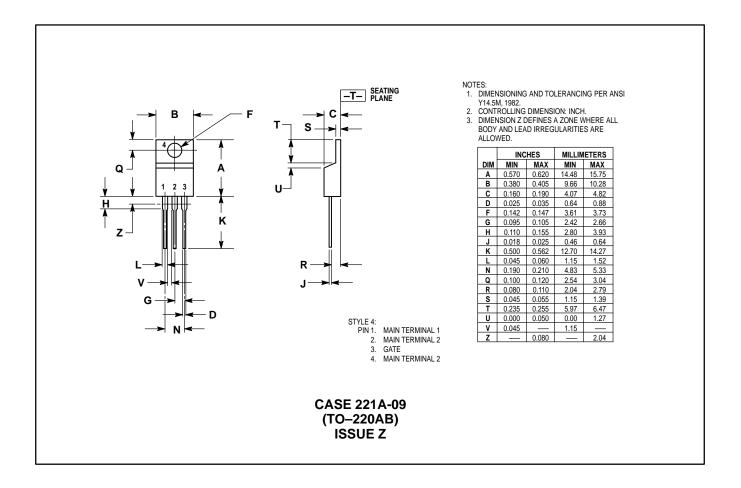
MAC12 SERIES

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS	•		•		
Peak On–State Voltage* ($I_{TM} = \pm 17 \text{ A}$)	V _{TM}	—	—	1.85	Volts
Continuous Gate Trigger Current ($V_D = 12 V, R_L = 100 \Omega$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	lgt	5.0 5.0 5.0	13 16 18	35 35 35	mA
Hold Current (V _D = 12 V, Gate Open, Initiating Current = \pm 150 mA)	ΙΗ	—	20	40	mA
Latch Current (V _D = 24 V, I _G = 35 mA) MT2(+), G(+); MT2(-), G(-) MT2(+), G(-)	ι		20 30	50 80	mA
Gate Trigger Voltage (V _D = 12 V, R _L = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	VGT	0.5 0.5 0.5	0.69 0.77 0.72	1.5 1.5 1.5	Volts
DYNAMIC CHARACTERISTICS					
Rate of Change of Commutating Current* ($V_D = 400 \text{ V}$, ITM = 4.4A, Commutating dv/dt = 18 V/µs, Gate Open, T _J = 125°C, f = 250 Hz, No Snubber)	(dv/dt)c	6.5	_	_	A/ms
Critical Rate of Rise of Off–State Voltage (V _D = Rated V _{DRM} , Exponential Waveform, Gate Open, T _J = 125°C)	dv/dt	250		_	V/µs

*Indicates Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

PACKAGE DIMENSIONS



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